

IRFBC30ASTRLPBF

IRFBC30ASTRLPBF Information



For Reference Only

Part Number IRFBC30ASTRLPBF Manufacturer Vishay Siliconix

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single MOSFET N-CH 600V 3.6A D2PAK

DescriptionMOSFET N-CH 600V 3.6A D2PAK**Package**TO-263-3, D2Pak (2 Leads + Tab), TO-263AB

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









IRFBC30ASTRLPBF Specifications

Manufacturer Part Number Manufacturer Vishay Siliconix Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single Package TO-263-3, D2Pak (2 Leads + Tab), TO Series - FET Type N-Channel Technology MOSFET (Metal Oxide) Drain to Source Voltage (Vdss) Current - Continuous Drain (Id) @ 25°C Drive Voltage (Max Rds On, Min Rds On) INV	
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Series - N-Channel Technology MOSFET (Metal Oxide) Drain to Source Voltage (Vdss) 600V Current - Continuous Drain (Id) @ 25°C 3.6A (Tc)	
FET Type Technology N-Channel MOSFET (Metal Oxide) Drain to Source Voltage (Vdss) Current - Continuous Drain (Id) @ 25°C 3.6A (Tc)	0-263AB
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Drive Voltage (Max Rds On, Min Rds On) 10V	
Vgs(th) (Max) @ Id 4.5V @ 250μA	
Gate Charge (Qg) (Max) @ Vgs 23nC @ 10V	
Input Capacitance (Ciss) (Max) @ Vds 510pF @ 25V	
Vgs (Max) ±30V	
FET Feature -	
Power Dissipation (Max) 74W (Tc)	
Rds On (Max) @ Id, Vgs 2.2 Ohm @ 2.2A, 10V	
Operating Temperature $-55^{\circ}\text{C} \sim 150^{\circ}\text{C} \text{ (TJ)}$	
Mounting Type Surface Mount	
Supplier Device Package D2PAK	
Package / Case TO-263-3, D2Pak (2 Leads + Tab), TO	L263AB
	2031 1D

IRFBC30ASTRLPBF Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IRFBC30ASTRLPBF Payment Methods



















IRFBC30ASTRLPBF Shipping Methods













If you have any question about IRFBC30ASTRLPBF, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com